

**Microsemi**

SCOTTSDALE DIVISION

UPT5Re3 – UPT48Re3**UPTB5e3 – UPTB48e3****SURFACE MOUNT TRANSIENT
VOLTAGE SUPPRESSORS****DESCRIPTION**

Microsemi's new Powermite UPT series transient voltage suppressors feature oxide-passivated chips, with high-temperature solder bonds for high surge capability, and negligible electrical degradation under repeated surge conditions. Both unidirectional and bidirectional configurations are available.

In addition to its size advantages, Powermite package includes a full metallic bottom (cathode) that eliminates the possibility of solder flux entrapment at assembly and a unique locking tab serving as an integral heat sink.

Innovative design makes this device fully compatible for use with automatic insertion equipment.

IMPORTANT: For the most current data, consult MICROSEMI's website: <http://www.microsemi.com>

APPEARANCE**DO-216AA****FEATURES**

- Powermite Package with standoff voltages 5 to 48 V
- Both unidirectional and Bidirectional Versions Available as "UPTR" and "UPTB" respectively
- Peak Pulse Power 1000 W for 8/20 μ s pulse
- Clamping Time in pico-seconds
- Integral heat sink / locking tabs
- Full metallic bottom eliminates flux entrapment
- Moisture classification is Level 1 with no dry pack required per IPC/JEDEC J-STD-020B
- Options for screening in accordance with MIL-PRF-19500 for JAN, JANTX, JANTXV, or JANS are available by adding MQ, MX, MV, or MSP prefixes respectively to part numbers, e.g. MXUPT15Re3, MVUPTB28e3, MSPUPT10Re3, etc.
- RoHS Compliant with e3 suffix part number

APPLICATIONS / BENEFITS

- Protects sensitive components such as IC's, CMOS, Bipolar, BiCMOS, ECL, DTL, T²L, etc.
- Protection from switching transients & induced RF
- New improved lower leakage current for the UPT5R & UPT5B
- Compliant to IEC61000-4-2 and IEC61000-4-4 for ESD and EFT protection respectively
- Secondary lightning protection per IEC61000-4-5 with 42 Ohms source impedance:
Class 1: UPTR/UPTB5 to 17
Class 2: UPTR/UPTB5 to 12

MAXIMUM RATINGS

- Operating and Storage Temperature: -65°C to +150°C
- Peak Pulse Power at 8/20 μ s (See Figure 1 and 2)
UPT5R & UPT5B: 600 Watts
UPT8R thru UPT48R: 1000 Watts
UPTB8 thru UPTB48: 1000 Watts
- Peak Pulse Power at 10/1000 μ s (See Figure 2).
UPT5R & UPT5B: 100 Watts
UPT8R thru UPT48R: 150 Watts
UPTB8 thru UPTB48: 150 Watts
- Impulse Repetition Rate (duty factor): 0.01%
- Thermal resistance: 15°C/W junction to base tab or 240°C/W junction to ambient when mounted on FR4 PC board with 1 oz copper
- Steady-State Power: 2.5 Watts (base tab \leq 112°C)
- Solder Temperatures: 260°C for 10 s (maximum)

MECHANICAL AND PACKAGING

- CASE: Void-free transfer molded thermosetting epoxy compound meeting UL94V-0
- FINISH: Annealed matte-Tin plating over copper and readily solderable per MIL-STD-750, method 2026
- POLARITY: Cathode to case (bottom TAB 1)
- MARKING: The last three digits of part number, e.g. UPT5R is T05•, UPT12R is T12•, UPT24 is T24•, UPTB5 is TB05•, UPTB12 is B12•, UPTB24 is B24•, etc. Please note dot suffix (for e3 suffix)
- WEIGHT: 0.016 gram (approximate)
- See package dimension on last page
- Tape & Reel option: Standard per EIA-481-B using 12 mm tape with 3,000 per 7 inch reel or 12,000 per 13 inch reel (add TR7 or TR13 suffix to part number)

**UPT5Re3 - UPT48Re3
UPTB5e3 - UPTB48e3**

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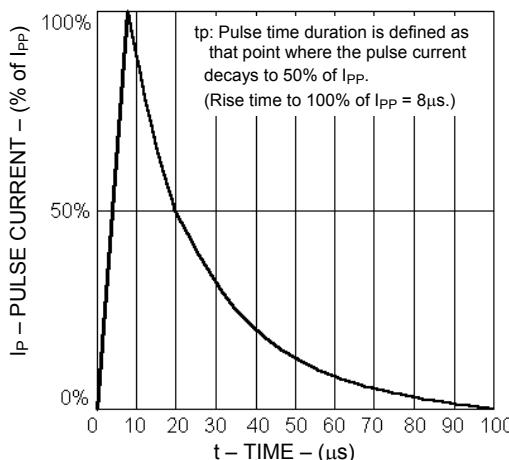
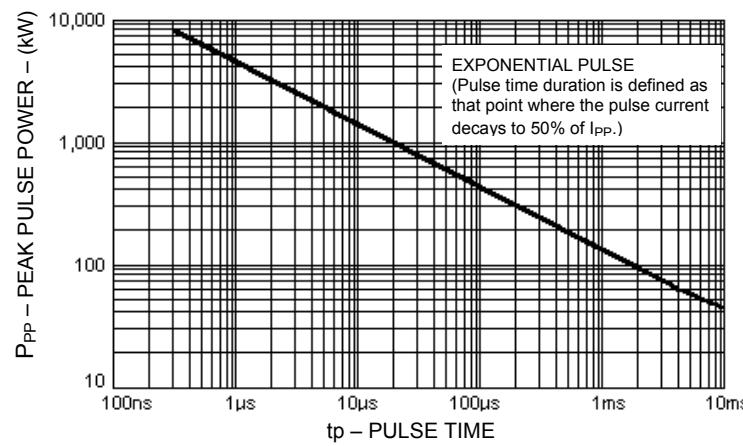
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UPT5Re3 – UPT48Re3**UPTB5e3 – UPTB48e3****SURFACE MOUNT TRANSIENT
VOLTAGE SUPPRESSORS****ELECTRICAL CHARACTERISTICS @ 25°C**

DEVICE TYPE		RATED STANOFF VOLTAGE V_{WM}	MINIMUM BREAKDOWN VOLTAGE $V_{(BR)} @ 1\text{ mA}$	MAXIMUM STANDBY CURRENT $I_D @ V_{WM}$	MAXIMUM PEAK PULSE CURRENT* I_{PP}	MAXIMUM CLAMPING VOLTAGE $V_C @ 10\text{ A}^*$	MAXIMUM TEMP. COEFFICIENT of $V_{(BR)}$ $\alpha_{V_{(BR)}}$
Unidirectional	Bi-directional	V	V	μA	A	V	%/°C
UPT5R	UPTB5	5	6.0	5	60	9.5	.030
UPT8R	UPTB8	8	9.0	2	62.1	13.7	.040
UPT10R	UPTB10	10	11.0	2	47.2	18.0	.045
UPT12R	UPTB12	12	13.8	1	40.3	21.6	.050
UPT15R	UPTB15	15	16.7	1	33.9	26.0	.055
UPT17R	UPTB17	17	19.0	1	30.8	29.2	.060
UPT24R	UPTB24	24	28.4	1	22.0	43.2	.070
UPT28R	UPTB28	28	31.0	1	19.2	47.8	.075
UPT33R	UPTB33	33	36.8	1	16.4	56.7	.080
UPT48R	UPTB48	48	54.0	1	11.2	84.3	.090

* See Figure 1 for I_{PP} waveform of 8/20 μs **SYMBOLS & DEFINITIONS**

Symbol	Definition
$V_{(BR)}$	Breakdown Voltage: The minimum voltage the device will exhibit at a specified current.
V_{WM}	Working Peak Standoff Voltage: The maximum peak voltage that can be applied over the operating temperature range.
P_{PP}	Peak Pulse Power: The peak power that can be applied for a specified pulse width and waveform.
I_D	Standby Current: The maximum current that will flow at the specified voltage and temperature.
I_{PP}	Peak Pulse Current: The peak current that can be applied for a specified pulse width and waveform.
C	Capacitance: The capacitance in picofarads of the TVS as defined @ 0 volts at a frequency of 1 MHz.

OUTLINE AND CIRCUIT**FIGURE 1**
Pulse Waveform for Exponential Surge**FIGURE 2**
Peak Pulse Power vs. Pulse Duration

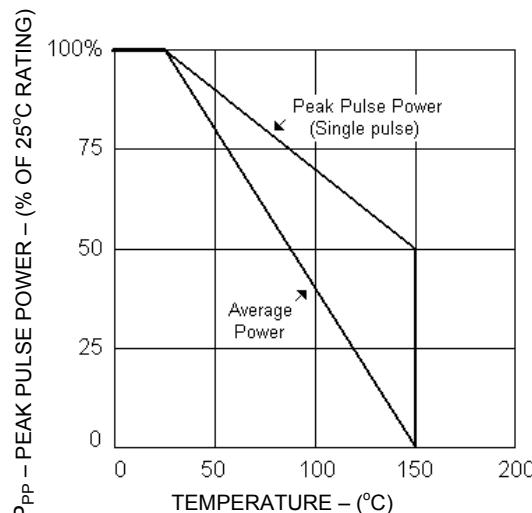


FIGURE 3
Derating Curve

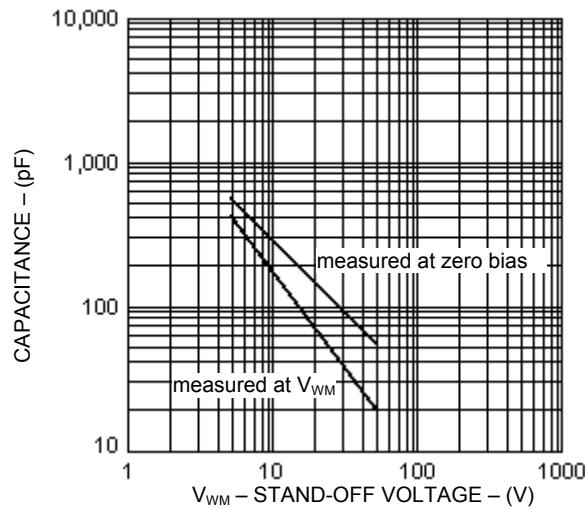
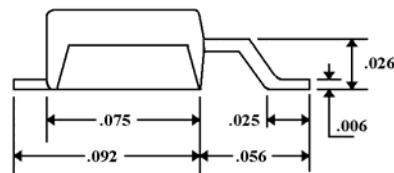
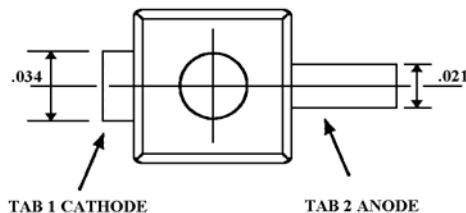
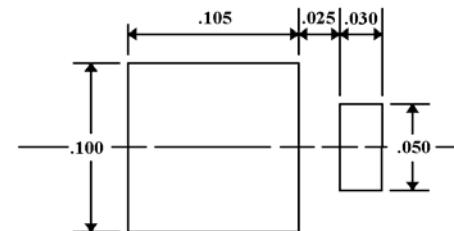
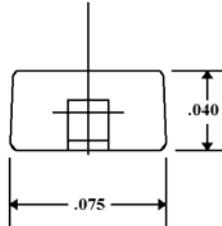


FIGURE 4
Typical Capacitance vs. Stand-Off Voltage

DIMENSIONS



All dimensions +/- .005 inches



MOUNTING PAD in inches